

CFast™ Cards

CFast™ cards combine the CompactFlash™ (CF) card form factor and the Serial ATA (SATA) interface into a single product. CFast™ cards can replace both HDDs and CompactFlash™ cards in applications requiring small form factors, high endurance and the ability to withstand shock, vibration, extreme temperatures (-40°C to +85°C), and rough environmental conditions. Swissbit's CFast™ cards provide

rugged and easy replaceable storage for embedded and industrial systems. The Swissbit CFast™ card portfolio covers the range from high end SLC based F-600 to the cost/performance optimized F-50. With an equal feature set as the 2.5" X-60 SSD, the F-60 MLC product and F-66 pSLC card are perfect devices for high performance and endurance and lowest total cost of ownership.



	●	●	●	★	●	○	●	★	●	●	●	★	○	●
F-600	●	●	●	★	●	○	●	★	●	●	●	★	○	●
F-60 / F-66	●	●	●	★	●	○	●	★	●	●	●	★	○	●
F-50 / F-56	●	●	●	★	●	○	●	★	●	●	●	●	○	○
F-240	●	●	●	★	○	○	○	★	●	★	●	○	●	○

★ Industry Leading; ● default implemented; ○ on request; ○ not available



F-600

F-60 / F-66

F-50 / F-56

F-240



GENERAL INFORMATION

TYPE	CFast™ CARD			
INTERFACE DATA TRANSFER MODE	CFast™ 2.0 – SATA III – 6 Gbit/s ATA8			CFast™ 1.0 – SATA II – 3 Gbit/s ATA7
CONNECTOR	CFast™ Type I			
OUTLINE DIMENSIONS	36.4 x 42.8 x 3.6 mm			
FLASH TYPE	SLC	MLC durabit™ / pSLC everbit™	MLC / pSLC	SLC
DENSITY RANGE	8 GB – 64 GB	MLC: 8 GB – 240 GB pSLC: 16 GB – 120 GB	MLC: 8 GB – 256 GB pSLC: 4 GB – 128 GB	2 GB – 64 GB
DATA RETENTION	10 years @ life begin 1 year @ life end			
ENDURANCE ENTERPRISE WL	8.7 TBW per GB drive capacity	0.6 TBW / 3.8 TBW per GB drive capacity	0.04 TBW / 0.32 TBW per GB drive capacity	100,000 P/E cycles (Flash cell level)

TEMPERATURE

OPERATING TEMPERATURE	Commercial: 0°C to +70°C Industrial: -40°C to +85°C
STORAGE TEMPERATURE	-40°C to +85°C

PERFORMANCE

BURST RATE (MB/S)	up to 600	up to 600	up to 600	up to 300
SEQUENTIAL READ (MB/S)	up to 520	up to 520 / 520	up to 500 / 510	up to 120
SEQUENTIAL WRITE (MB/S)	up to 245	up to 180 / 415	up to 330 / 415	up to 120
RANDOM 4KB READ (IOPS)	up to 76,000	up to 72,000 / 80,000	up to 53,000 / 32,000	up to 3,200
RANDOM 4KB WRITE (IOPS)	up to 54,000	up to 43,000 / 75,000	up to 74,000 / 66,000	up to 75

ROBUSTNESS

MTBF	≥ 2,000,000 hours	≥ 2,500,000 hours
SHOCK	1,500 G, 0.5 ms	1,500 G
VIBRATION	50 G, 131-2,000 Hz	20 G
HUMIDITY	85 % RH 85°C, 1,000 hrs	

ELECTRICAL DATA

VOLTAGE	3.3 V ± 5 %			
POWER CONSUMPTION	typ 450 mA max 715 mA Idle 105 mA DEVSLP 35 mA	typ 400 mA max 495 mA Idle 110 mA DEVSLP 35 mA	typ 290 mA max 420 mA Idle 75 mA DEVSLP 35 mA	typ 500 mA max 960 mA Idle 115 mA PHYSLP <25 mA

FEATURE LIST

FEATURES & TOOLS	Proven Power Fail Safety NCQ, TRIM Advanced Wear Leveling & Bad Block management In-field firmware update SBLTM Tool & SDK for S.M.A.R.T. based Life Time Monitoring	Proven Power Fail Safety Sophisticated Wear Leveling & Bad Block management Read Disturb Management TRIM Low Power Consumption Security & SBZoneProtection features available SBLTM Tool & SDK for S.M.A.R.T. based Life Time Monitoring
PART NUMBER	SFCxxxxHvAAxss-t-dd-rrr-ccc	SFCxxxxHvBVxss-t-dd-rrr-ccc